



# Thyristor \ Diode Module

$V_{RRM} = 2 \times 1600 \text{ V}$

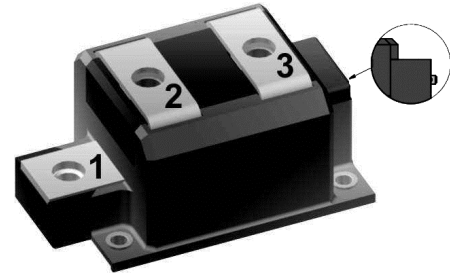
$I_{TAV} = 700 \text{ A}$

$V_T = 1.11 \text{ V}$

Phase leg

Part number

**MCMA700PD1600CB**



Backside: isolated

E72873



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al<sub>2</sub>O<sub>3</sub>-ceramic

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: ComPack

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: Copper internally DCB isolated
- Advanced power cycling
- Phase Change Material available

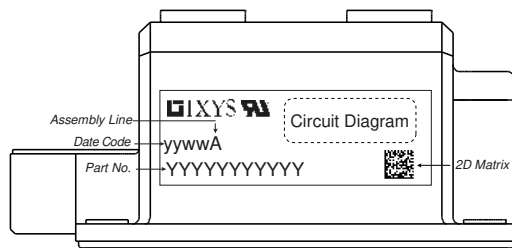
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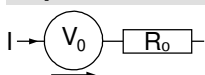
Rectifier			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^{\circ}C$			1700	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^{\circ}C$			1600	V
$I_{RD}$	reverse current, drain current	$V_{R/D} = 1600 V$	$T_{VJ} = 25^{\circ}C$		2	mA
		$V_{R/D} = 1600 V$	$T_{VJ} = 125^{\circ}C$		40	mA
$V_T$	forward voltage drop	$I_T = 700 A$	$T_{VJ} = 25^{\circ}C$		1.16	V
		$I_T = 1400 A$			1.41	V
		$I_T = 700 A$	$T_{VJ} = 125^{\circ}C$		1.11	V
		$I_T = 1400 A$			1.41	V
$I_{TAV}$	average forward current	$T_C = 85^{\circ}C$ 180° sine	$T_{VJ} = 140^{\circ}C$		700	A
$V_{T0}$	threshold voltage	} for power loss calculation only	$T_{VJ} = 140^{\circ}C$		0.82	V
$r_T$	slope resistance				0.4	mΩ
$R_{thJC}$	thermal resistance junction to case				0.05	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.02		K/W
$P_{tot}$	total power dissipation		$T_C = 25^{\circ}C$		2300	W
$I_{TSM}$	max. forward surge current	$t = 10 ms; (50 Hz), sine$	$T_{VJ} = 45^{\circ}C$		19.0	kA
		$t = 8,3 ms; (60 Hz), sine$	$V_R = 0 V$		20.5	kA
		$t = 10 ms; (50 Hz), sine$	$T_{VJ} = 140^{\circ}C$		16.2	kA
		$t = 8,3 ms; (60 Hz), sine$	$V_R = 0 V$		17.4	kA
$I^2t$	value for fusing	$t = 10 ms; (50 Hz), sine$	$T_{VJ} = 45^{\circ}C$		1.81	MA <sup>2</sup> s
		$t = 8,3 ms; (60 Hz), sine$	$V_R = 0 V$		1.75	MA <sup>2</sup> s
		$t = 10 ms; (50 Hz), sine$	$T_{VJ} = 140^{\circ}C$		1.30	MA <sup>2</sup> s
		$t = 8,3 ms; (60 Hz), sine$	$V_R = 0 V$		1.27	MA <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		876	pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$	$T_C = 140^{\circ}C$		240	W
		$t_p = 300 \mu s$			120	W
$P_{GAV}$	average gate power dissipation				40	W
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 140^{\circ}C; f = 50 Hz$ repetitive, $I_T = 2100 A$			100	A/μs
		$t_p = 200 \mu s; di_G/dt = 1 A/\mu s;$ $I_G = 1 A; V = 2/3 V_{DRM}$ non-repet., $I_T = 700 A$			500	A/μs
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = 2/3 V_{DRM}$ $R_{GK} = \infty; method 1 (linear voltage rise)$	$T_{VJ} = 140^{\circ}C$		1000	V/μs
$V_{GT}$	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$		2	V
			$T_{VJ} = -40^{\circ}C$		3	V
$I_{GT}$	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$		300	mA
			$T_{VJ} = -40^{\circ}C$		400	mA
$V_{GD}$	gate non-trigger voltage	$V_D = 2/3 V_{DRM}$	$T_{VJ} = 140^{\circ}C$		0.25	V
$I_{GD}$	gate non-trigger current				10	mA
$I_L$	latching current	$t_p = 30 \mu s$	$T_{VJ} = 25^{\circ}C$		400	mA
		$I_G = 1 A; di_G/dt = 1 A/\mu s$				
$I_H$	holding current	$V_D = 6 V R_{GK} = \infty$	$T_{VJ} = 25^{\circ}C$		300	mA
$t_{gd}$	gate controlled delay time	$V_D = 1/2 V_{DRM}$	$T_{VJ} = 25^{\circ}C$		2	μs
		$I_G = 1 A; di_G/dt = 1 A/\mu s$				
$t_q$	turn-off time	$V_R = 100 V; I_T = 700 A; V = 2/3 V_{DRM}$ $di/dt = 10 A/\mu s dv/dt = 50 V/\mu s t_p = 200 \mu s$	$T_{VJ} = 125^{\circ}C$		350	μs

Package ComPack		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			1200	A
$T_{VJ}$	virtual junction temperature		-40		140	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		125	°C
<b>Weight</b>				500		g
$M_D$	mounting torque		3		5	Nm
$M_T$	terminal torque		12		14	Nm
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	21.0			mm
$d_{Spb/Apb}$		terminal to backside	18.0			mm
$V_{ISOL}$	isolation voltage	t = 1 second	4800			V
		t = 1 minute	4000			V


**Part description**

- M = Module
- C = Thyristor (SCR)
- M = Thyristor
- A = (up to 1800V)
- 700 = Current Rating [A]
- PD = Phase leg
- 1600 = Reverse Voltage [V]
- CB = ComPack
- = Hyphen
- PC = Phase Change Material

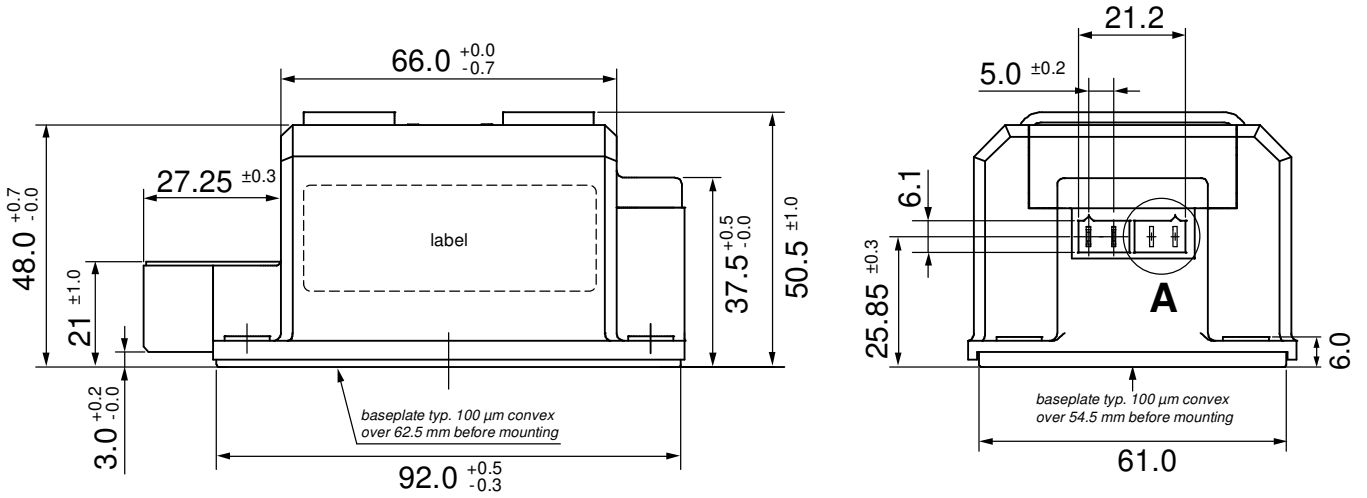
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA700PD1600CB	MCMA700PD1600CB	Box	3	513842
Alternative	MCMA700PD1600CB-PC	MCMA700PD1600CB	Box	3	518554

**Equivalent Circuits for Simulation**
*\* on die level*
 $T_{VJ} = 140^{\circ}\text{C}$ 

**Thyristor**

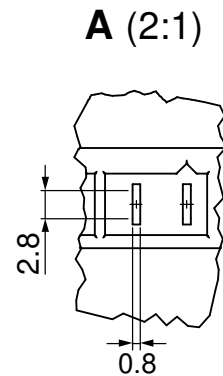
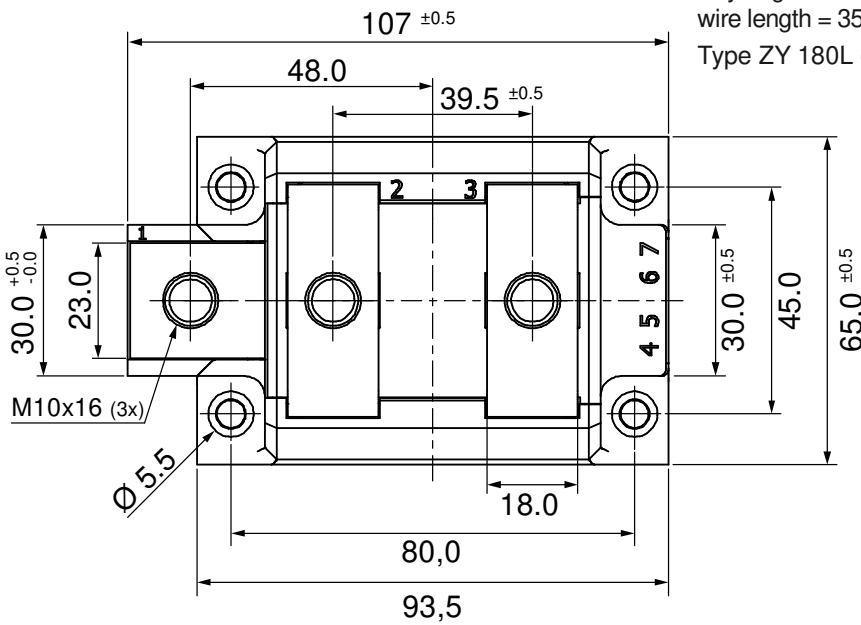
$V_{0\ max}$	threshold voltage	0.82	V
$R_{0\ max}$	slope resistance *	0.21	mΩ



**Outlines ComPack**



Optional accessories for modules  
Keyed gate/cathode twin plug with  
wire length = 350 mm, gate = white, cathode = red  
Type ZY 180L (L = Left for pin pair 4/5) UL 758, style 3751



## Thyristor

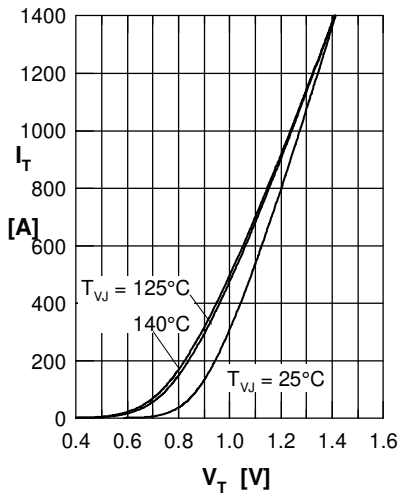


Fig. 1 Forward characteristics

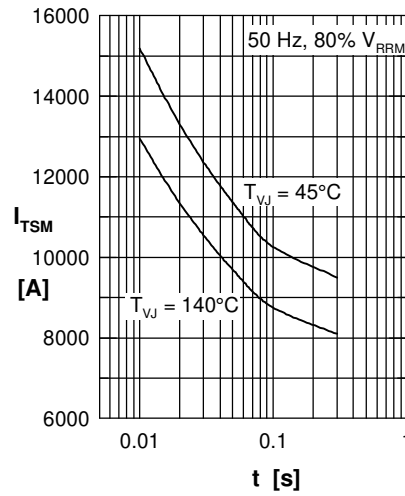


Fig. 2 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : duration

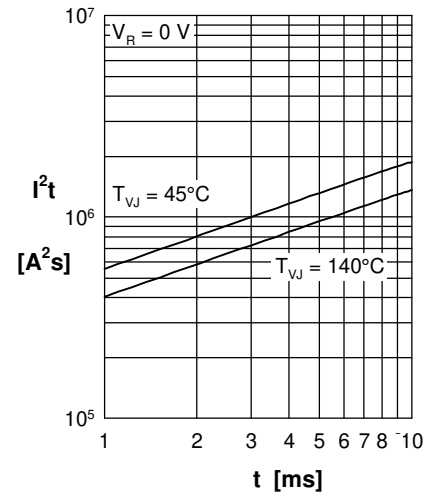


Fig. 3  $I^2t$  versus time (1-10 s)

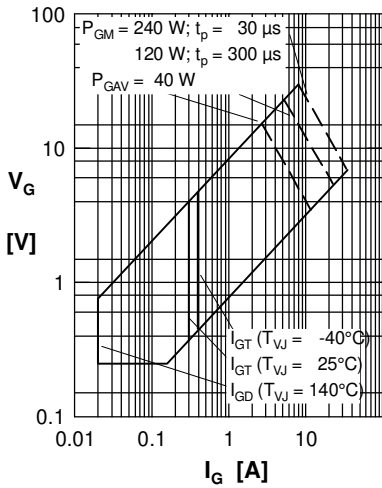


Fig. 4 Gate voltage & gate current

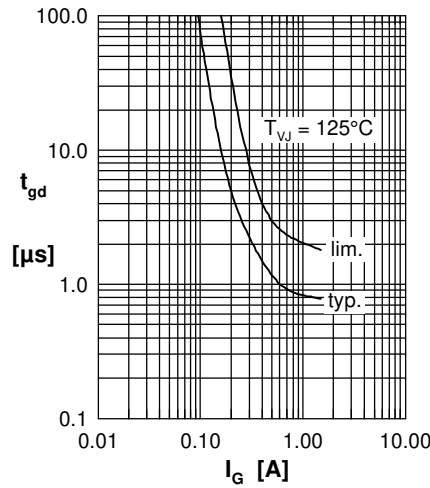


Fig. 5 Gate controlled delay time  $t_{gd}$

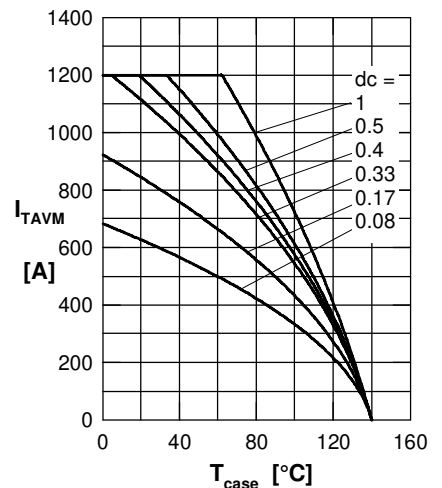


Fig. 6 Max. forward current at case temperature

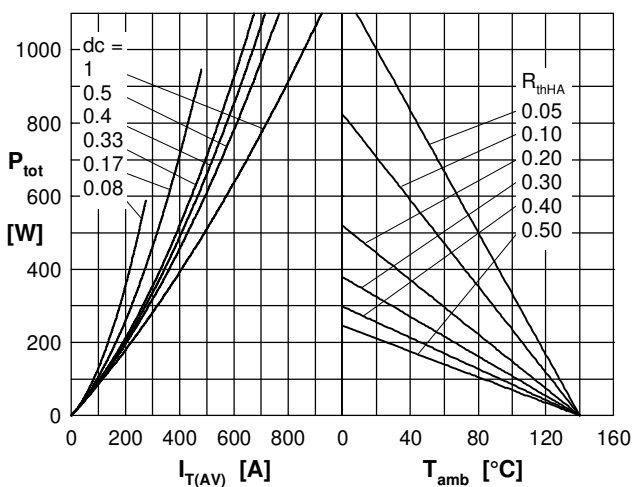


Fig. 7a Power dissipation versus direct output current  
 Fig. 7b and ambient temperature

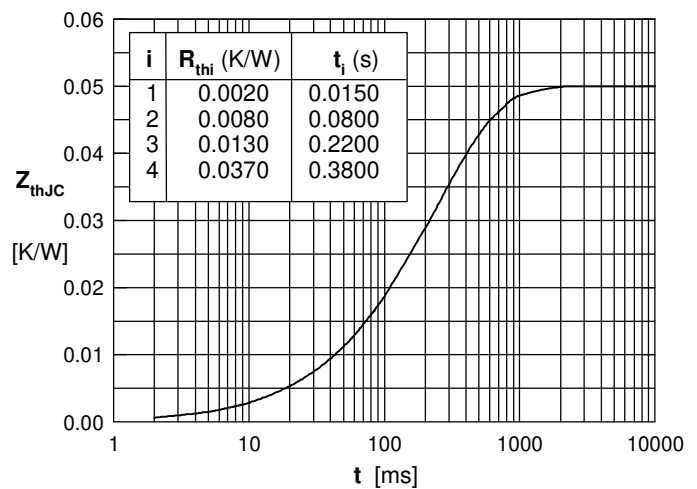


Fig. 8 Transient thermal impedance junction to case

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- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
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